

# Photo FET Optocouplers H11F1M, H11F2M, H11F3M

# **General Description**

The H11FXM series consists of a Gallium-Aluminum-Arsenide IRED emitting diode coupled to a symmetrical bilateral silicon photo-detector. The detector is electrically isolated from the input and performs like an ideal isolated FET designed for distortion-free control of low level AC and DC analog signals. The H11FXM series devices are mounted in dual in-line packages.

#### **Features**

- As a Remote Variable Resistor:
  - $\leq 100 \Omega$  to  $\geq 300 M\Omega$
  - ◆ ≤15 pF Shunt Capacitance
  - ≥100 GΩ I/O Isolation Resistance
- As an Analog Switch:
  - Extremely Low Offset Voltage
  - ullet 60  $V_{pk-pk}$  Signal Capability
  - No Charge Injection or Latch-Up
  - UL Recognized (File #E90700)
- These are Pb-Free Devices

# **Application**

- As a Remote Variable Resistor:
  - ◆ Isolated Variable Attenuator
  - Automatic Gain Control
  - Active Filter Fine Tuning/Band Switching
- As an Analog Switch:
  - Isolated Sample and Hold Circuit
  - Multiplexed, Optically Isolated A/D Conversion



PDIP6 8.51x6.35, 2.54P CASE 646BX

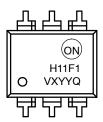


PDIP6 8.51x6.35, 2.54P CASE 646BY



PDIP6 8.51x6.35, 2.54P CASE 646BZ

# **MARKING DIAGRAM**



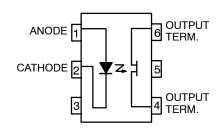
H11F1 = Specific Device Code

V = VDE Mark (Only appears on parts ordered with VDE option – See order entry table)

X = One-Digit Year Code, e.g., "7" YY = Two Digit Work Week Ranging from "01" to "53"

Q = Assembly Package Code

# **SCHEMATIC**



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 6 of this data sheet

1

# **SAFETY AND INSULATION RATINGS**

(As per DIN EN/IEC 60747–5–5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.)

Parameter	Characteristics	
Installation Classifications per DIN VDE 0110/1.89 Table 1	tion Classifications per DIN VDE 0110/1.89 Table 1 < 150 Vrms	
	< 300 Vrms	I–IV
Climatic Classification		55/100/21
Pollution Degree (DIN VDE 0110/1.89)		2
Comparative Tracking Index		175

Symbol	Parameter	Value	Unit
V <sub>PR</sub>	Input to Output Test Voltage, Method A, $V_{IORM} \times 1.6 = V_{PR}$ , Type and Sample Test with $t_m = 10$ s, Partial Discharge < 5 pC	1360	$V_{ m peak}$
	Input to Output Test Voltage, Method B, $V_{IORM} \times 1.875 = V_{PR}$ , 100% Production Test with $t_m = 1$ s, Partial Discharge < 5 pC	1594	$V_{ m peak}$
V <sub>IORM</sub>	Maximum Working Insulation Voltage	850	$V_{peak}$
V <sub>IOTM</sub>	Highest Allowable Over Voltage	6,000	$V_{peak}$
	External Creepage	≥7	mm
	External Clearance	≥7	mm
	External Clearance (for Option TV, 0.4" Lead Spacing)	≥10	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥0.5	mm
T <sub>S</sub>	Case Temperature (Note 1)	175	°C
I <sub>S,INPUT</sub>	Input Current (Note 1)	350	mA
P <sub>S,OUTPUT</sub>	Output Power (Note 1)	800	mW
R <sub>IO</sub>	Insulation Resistance at Ts, V <sub>IO</sub> = 500 V (Note 1)	>10 <sup>9</sup>	Ω

<sup>1.</sup> Safety limit values - maximum values allowed in the event of a failure.

# ABSOLUTE MAXIMUM RATINGS ( $T_A = 25$ °C unless otherwise specified)

Symbol	Parameter	Value	Unit	
TOTAL DEV	ICE			
T <sub>STG</sub>	Storage Temperature		-40 to +125	°C
T <sub>OPR</sub>	Operating Temperature		-40 to +100	°C
T <sub>SOL</sub>	Lead Solder Temperature		260 for 10 seconds	°C
EMITTER				
I <sub>F</sub>	Continuous Forward Current	60	mA	
V <sub>R</sub>	Reverse Voltage	5	V	
I <sub>F</sub> (pk)	Forward Current – Peak (10 μs Pulse, 1% Duty Cycle)	1	Α	
P <sub>D</sub>	LED Power Dissipation Ambient 25°C Ambient		100	mW
	Derate Linearly from 25°C		1.33	mW/°C
DETECTOR				
$P_{D}$	Detector Power Dissipation at 25°C		300	mW
	Derate Linearly from 25°C		4.0	mW/°C
BV <sub>4-6</sub>	Breakdown Voltage (Either Polarity) H11F1M, H11F2M		±30	V
		H11F3M	±15	V
I <sub>4-6</sub>	Continuous Detector Current (Either Polarity)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

# INDIVIDUAL COMPONENT CHARACTERISTICS

Symbol	Paran	neter	Test Conditions	Min	Тур*	Max	Unit
EMITTER							
V <sub>F</sub>	Input Forward Voltage		I <sub>F</sub> = 16 mA	-	1.3	1.75	V
I <sub>R</sub>	Reverse Leakage Curre	nt	V <sub>R</sub> = 5 V	-	_	10	μΑ
СЈ	Capacitance	Capacitance		-	50	-	pF
OUTPUT DE	DUTPUT DETECTOR						
BV <sub>4-6</sub>	Breakdown Voltage Either Polarity	H11F1M, H11F2M	$I_{4-6} = 10 \ \mu\text{A}, \ I_F = 0$	30	_	-	V
		H11F3M		15	-	-	
I <sub>4-6</sub>	Off-State Dark Current		V <sub>4-6</sub> = 15 V, I <sub>F</sub> = 0	-	-	50	nA
			$V_{4-6} = 15 \text{ V, I}_F = 0,$ $T_A = 100^{\circ}\text{C}$	-	_	50	μΑ
R <sub>4-6</sub>	Off-State Resistance		V <sub>4-6</sub> = 15 V, I <sub>F</sub> = 0	300	_	-	МΩ
C <sub>4-6</sub>	Capacitance		$V_{4-6} = 15 \text{ V}, I_F = 0,$ f = 1 MHz	-	_	15	pF

# TRANSFER CHARACTERISTICS

Symbol	Characte	ristics	Test Conditions	Min	Typ*	Max	Unit
C CHARA	CTERISTICS		•				
R <sub>4-6</sub>	On-State Resistance	H11F1M	$I_F = 16 \text{ mA}, I_{4-6} = 100 \mu\text{A}$	_	-	200	Ω
		H11F2M		_	-	330	
		H11F3M		-	-	470	
R <sub>6-4</sub>	On-State Resistance	H11F1M	$I_F = 16 \text{ mA}, I_{6-4} = 100 \mu\text{A}$	-	-	200	Ω
		H11F2M		-	-	330	
		H11F3M	7	-	-	470	
	Resistance, Non-Linearit	y and Assymetry	$I_F = 16 \text{ mA}, I_{4-6} = 25 \mu\text{A RMS}, f = 1 \text{ kHz}$	_	2	_	%
C CHARA	CTERISTICS		•				
t <sub>on</sub>	Turn-On Time		$R_L = 50 \ \Omega, I_F = 16 \ mA, V_{4-6} = 5 \ V$	_	_	45	μs
t <sub>off</sub>	Turn-Off Time		$R_L$ = 50 Ω, $I_F$ = 16 mA, $V_{4-6}$ = 5 V	_	-	45	μs

#### **ISOLATION CHARACTERISTICS**

Symbol	Characteristics	Test Conditions	Min	Тур*	Max	Unit
V <sub>ISO</sub>	Input-Output Isolation Voltage	t = 1 Minute	4170	-	-	VAC <sub>RMS</sub>
R <sub>ISO</sub>	Isolation Resistance	V <sub>I-O</sub> = 500 VDC	10 <sup>11</sup>	-	-	Ω
C <sub>ISO</sub>	Isolation Capacitance	f = 1 MHz	-	0.2	-	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. \*All Typical values at T<sub>A</sub>= 25°C.

# **TYPICAL PERFORMANCE CURVES**

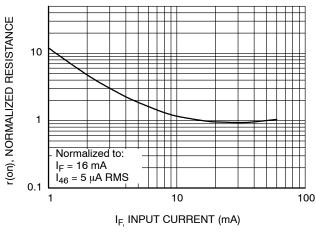


Figure 1. Resistance vs. Input Current

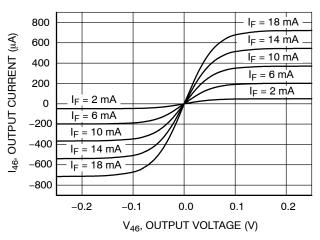


Figure 2. Output Characteristics

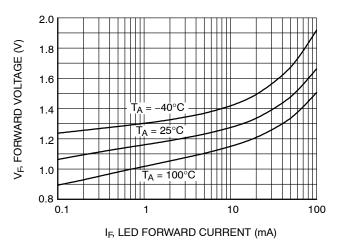


Figure 3. LED Forward Voltage vs. Forward Current

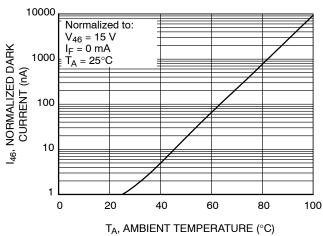


Figure 4. Off-State Current vs. Ambient Temperature

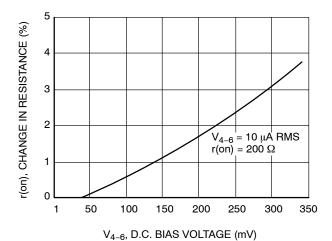
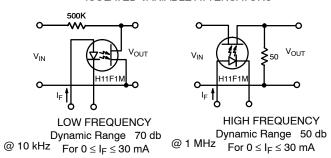


Figure 5. Resistive Non-Linearity vs. D.C. Bias

#### TYPICAL APPLICATIONS

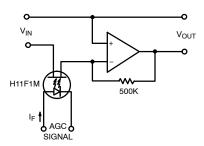
#### As a Variable Resistor

# ISOLATED VARIABLE ATTENUATORS



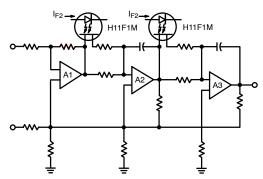
Distortion free attenuation of low level A.C. signals is accomplished by varying the IRED current, IF Note the wide dynamic range and absence of coupling capacitors; D.C. level shifting or parasitic feedback to the controlling function.

#### AUTOMATIC GAIN CONTROL



This simple circuit provides over 70db of stable gain control for an AGC signal range of from 0 to 30mA. This basic circuit can be used to provide programmable fade and attack for electronic music.

#### ACTIVE FILTER FINE TUNING/BAND SWITCHING

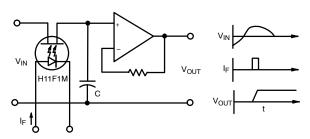


IF2 ADJUSTS f<sub>1</sub>, IF2 ADJUSTS f<sub>2</sub>

The linearity of resistance and the low offset voltage of the H11FXM allows the remote tuning or band-switching of active filters without switching glitches or distortion. This schematic illustrates the concept, with current to the H11F1M IRED 's controlling the filter's transfer characteristic.

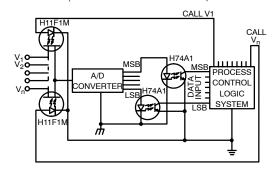
#### As an Analog Signal Switch

ISOLATED VARIABLE ATTENUATORS



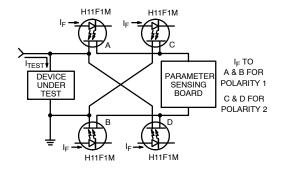
Accuracy and range are improved over conventional FET switches because the H11FXM has no charge injection from the control signal. The H11FXM also provides switching of either polarity input signal up to 30V magnitude.

#### MULTIPLEXED, OPTICALLY-ISSOLATED A/D CONVERSION



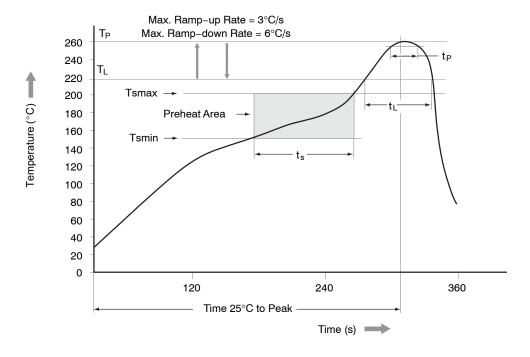
The optical isolation, linearity and low offset voltage of the H11FXM allows the remote multiplexing of low level analog signals from such transducers as thermocouplers, Hall effect devices, strain gauges, etc. to a single A/D converter.

#### TEST EQUIPMENT - KELVIN CONTACT POLARITY



In many test equipment designs the auto polarity function uses reed relay contacts to switch the Kelvin Contact polarity. These reeds are normally one of the highest maintenance cost items due to sticking contacts and mechanical problems. The totally solid–State H11FXM eliminates these troubles while providing faster switching.

# **REFLOW PROFILE**



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (t <sub>S</sub> ) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t <sub>L</sub> to t <sub>P</sub> )	3°C/seconds max.
Liquidous Temperature (T <sub>L</sub> )	217°C
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60-150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t <sub>P</sub> ) within 5°C of 260°C	30 seconds
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/seconds max.
Time 25°C to Peak Temperature	8 minutes max.

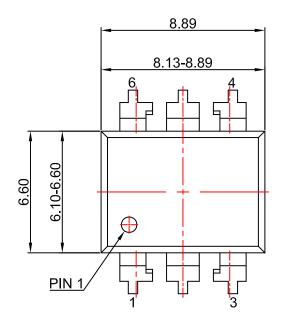
# **ORDERING INFORMATION**

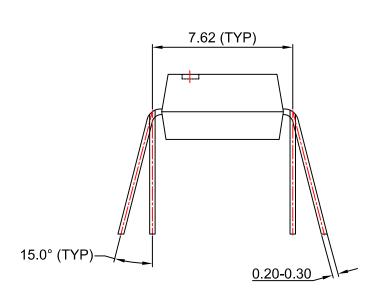
Option	Order Entry Identifier (Example)	Description
No option	H11F1M	Standard Through Hole Device
S	H11F1SM	Surface Mount Lead Bend
SR2	H11F1SR2M	Surface Mount; Tape and Reel
V	H11F1VM	IEC60747-5-5 approval
TV	H11F1TVM	IEC60747-5-5 approval, 0.4" Lead Spacing
SV	H11F1SVM	IEC60747-5-5 approval, Surface Mount
SR2V	H11F1SR2VM	IEC60747-5-5 approval, Surface Mount, Tape and Reel

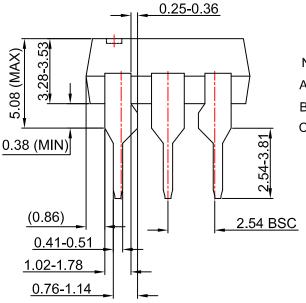


# PDIP6 8.51x6.35, 2.54P CASE 646BX ISSUE O

**DATE 31 JUL 2016** 







# NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION

DOCUMENT NUMBER:	98AON13449G	Electronic versions are uncontrolled except when accessed directly from the Document Reposit Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	PDIP6 8.51X6.35, 2.54P		PAGE 1 OF 1	

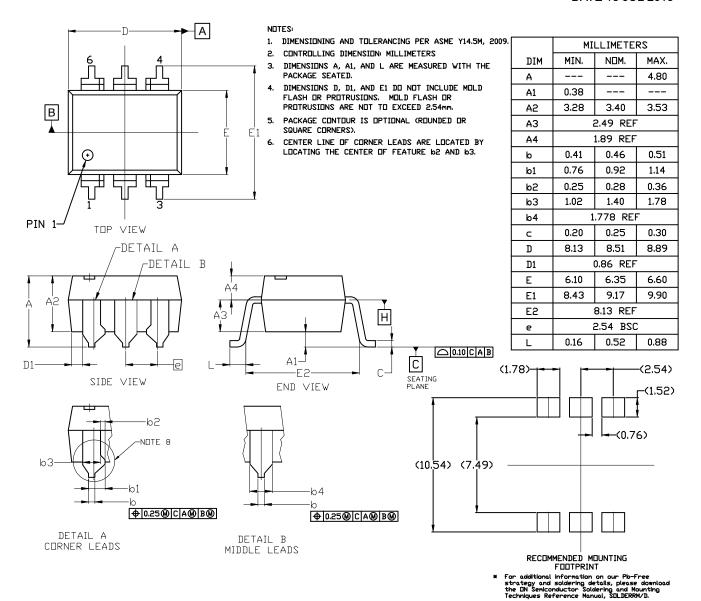
onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.





# PDIP6 8.51x6.35, 2.54P CASE 646BY **ISSUE A**

**DATE 15 JUL 2019** 



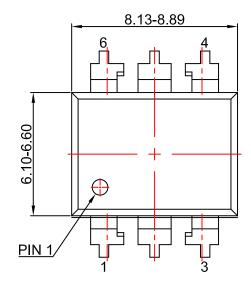
DOCUMENT NUMBER:	98AON13450G	Electronic versions are uncontrolled except when accessed directly from the Document Reposit Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	PDIP6 8.51x6.35, 2.54P		PAGE 1 OF 1	

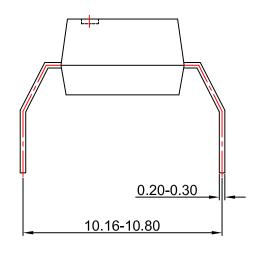
onsemi and Onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries, onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

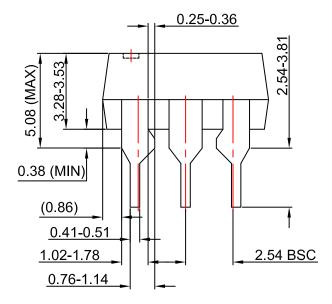


# PDIP6 8.51x6.35, 2.54P CASE 646BZ ISSUE O

**DATE 31 JUL 2016** 







# NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION

DOCUMENT NUMBER:	98AON13451G	Electronic versions are uncontrolled except when accessed directly from the Document Reposite Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	PDIP6 8.51X6.35, 2.54P		PAGE 1 OF 1	

onsemi and ONSEMi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI., and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems. or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$ 

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales